

SURFACE MOUNT SCHOTTKY BARRIER DIODES

VOLTAGE RANGE: 20 - 100V CURRENT: 2.0 A

Features

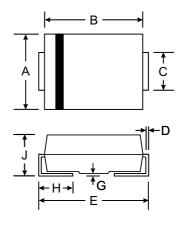
- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability Classification Rating 94V-O

Mechanical Data

- Case: SMB/DO-214AA, Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.093 grams (approx.)







SMB(DO-214AA)							
Dim	Min	Max					
Α	3.30	3.94					
В	4.06	4.70					
С	1.91	2.21					
D	0.15	0.31					
E	5.00	5.59					
G	0.10	0.20					
Н	0.76	1.52					
J	2.00	2.62					
All Dimensions in mm							

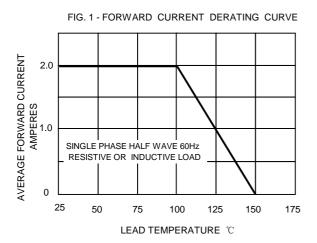
Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

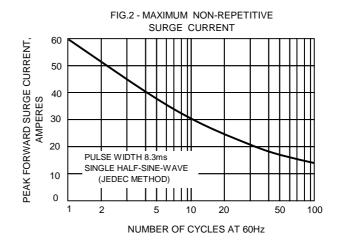
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

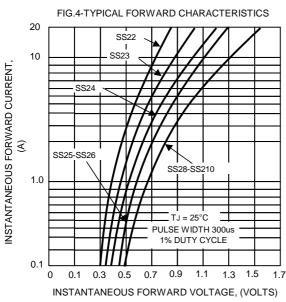
Characteristic	Symbol	SS22	SS23	SS24	SS25	SS26	SS28	SS29	SS210	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	20	30	40	50	60	80	90	100	V
RMS Reverse Voltage	VR(RMS)	14	21	28	35	42	56	64	71	V
Average Rectified Output Current @T _L = 105°C	lo	2.0							Α	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	50							А	
Forward Voltage @I _F = 2.0A	VFM	0.50 0.70 0.85							V	
	lкм	0.5 20							mA	
Typical Thermal Resistance (Note 1)	RθJL RθJA	17 75							°C/W	
Operating Temperature Range	Tj	-65 to +125							°C	
Storage Temperature Range	Тѕтс	-65 to +150							•	°C

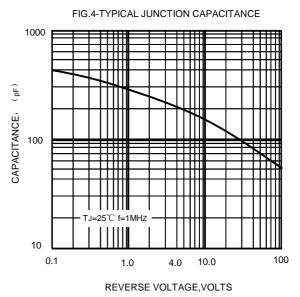
Note: 1. Mounted on P.C. Board with 8.0mm² copper pad area.



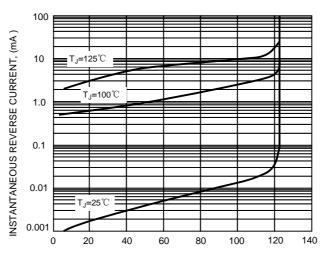












PERCENT RATED PEAK REVERSE VOLTAGE,(%)